

Silicon Carbide (SiC)  
Schottky Diode



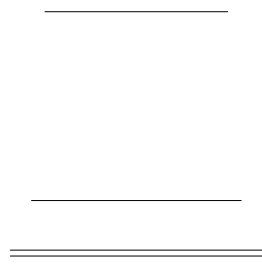
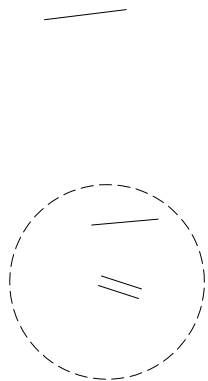


# FFSB2065B-F085

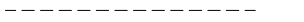
TYPICAL CHARACTERISTICS ( $T_J = 25$

**D<sup>2</sup>PAK2 (TO-263-2L)**  
CASE 418BK  
ISSUE O

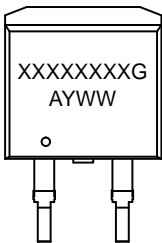
DATE 02 AUG 2018



DET/



**GENERIC  
MARKING DIAGRAM\***



- XXX = Specific Device Code
- A = Assembly Location
- Y = Year
- WW = Work Week
- G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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